Quad 2-input NAND gate Rev. 3 — 30 April 2021

**Product data sheet** 

### 1. General description

The 74ALVC00-Q100 is a quad 2-input NAND gate.

Schmitt trigger action on all inputs makes the device tolerant of slow rise and fall times.

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 3) and is suitable for use in automotive applications.

### 2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 3)
   Specified from -40 °C to +85 °C
- Wide supply voltage range from 1.65 V to 3.6 V
- 3.6 V tolerant inputs/outputs
- CMOS low power consumption
- Direct interface with TTL levels (2.7 V to 3.6 V)
- Power-down mode
- Latch-up performance exceeds 250 mA
  - Complies with JEDEC standards:
  - JESD8-7 (1.65 V to 1.95 V)
  - JESD8-5 (2.3 V to 2.7 V)
  - JESD8B (2.7 V to 3.6 V)
- ESD protection:
  - MIL-STD-883, method 3015 exceeds 2000 V
  - HBM JESD22-A114F exceeds 2000 V
  - MM JESD22-A115-A exceeds 200 V (C = 200 pF, R = 0 Ω)
- Multiple package options
- DHVQFN package with Side-Wettable Flanks enabling Automatic Optical Inspection (AOI) of solder joints

### 3. Ordering information

#### Table 1. Ordering information

Type number	Package	nge					
	Temperature range	Name	Description	Version			
74ALVC00D-Q100	-40 °C to +85 °C	SO14	plastic small outline package; 14 leads; body width 3.9 mm	SOT108-1			
74ALVC00PW-Q100	-40 °C to +85 °C	TSSOP14	plastic thin shrink small outline package; 14 leads; body width 4.4 mm	SOT402-1			
74ALVC00BQ-Q100	-40 °C to +85 °C	DHVQFN14	plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 14 terminals; body 2.5 × 3 × 0.85 mm	SOT762-1			

# nexperia

#### **Quad 2-input NAND gate**

74ALVC00 V<sub>CC</sub>

> 14  $\left( - \right)$

GND<sup>(1)</sup>

GND 37

Pin configuration SOT762-1 (DHVQFN14)

Transparent top view

(1) This is not a ground pin. There is no electrical or mechanical requirement to solder the pad. In case

soldered, the solder land should remain floating or

60

(13 4B

(12

(11

(10 3B

(9 3A

4A

4Y

aaa-032330

terminal 1 index area

> 1B 2

1Y

2A

2B

2Y 6

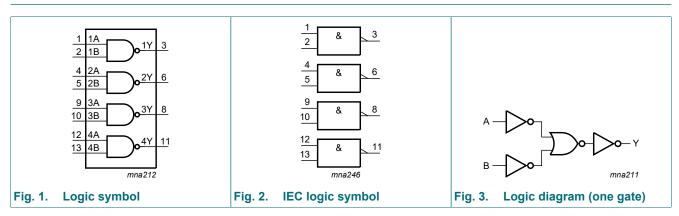
connected to GND

3)

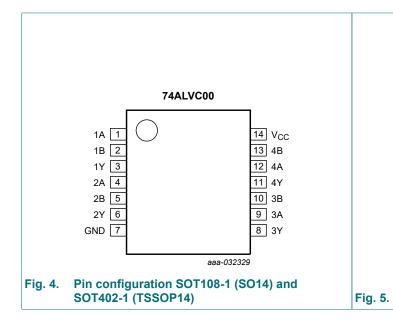
4)

5)

### 4. Functional diagram



### 5. Pinning information



#### 5.1. Pinning



5	5.2. Pin description				
Table 2. Pin description					
Symbol	Pin	Description			
1A to 4A	1, 4, 9, 12	data input			
1B to 4B	2, 5, 10, 13	data input			
1Y to 4Y	3, 6, 8, 11	data output			
GND	7	ground (0 V)			
V <sub>CC</sub>	14	supply voltage			

74ALVC00\_Q100

### 6. Functional description

#### Table 3. Function selection

H = HIGH voltage level; L = LOW voltage level; X = don't care

Input	Output	
nA	nB	nY
L	X	Н
Х	L	Н
Н	Н	L

### 7. Limiting values

#### Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>CC</sub>	supply voltage			-0.5	+4.6	V
I <sub>IK</sub>	input clamping current	V <sub>I</sub> < 0 V		-50	-	mA
VI	input voltage		[1]	-0.5	+4.6	V
I <sub>ОК</sub>	output clamping current	$V_{\rm O}$ > $V_{\rm CC}$ or $V_{\rm O}$ < 0 V		-	±50	mA
Vo	output voltage	output HIGH or LOW state	[1]	-0.5	V <sub>CC</sub> + 0.5	V
		output 3-state		-0.5	+4.6	V
		power-down mode; $V_{CC}$ = 0 V		-0.5	+4.6	V
I <sub>O</sub>	output current	$V_{O} = 0 V$ to $V_{CC}$		-	±50	mA
I <sub>CC</sub>	supply current			-	100	mA
I <sub>GND</sub>	ground current			-100	-	mA
T <sub>stg</sub>	storage temperature			-65	+150	°C
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> = -40 °C to +85 °C	[2]	-	500	mW

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For SOT402-1 (TSSOP14) package: Ptot derates linearly with 7.3 mW/K above 81 °C.

### 8. Recommended operating conditions

#### Table 5. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	supply voltage		1.65	3.6	V
VI	input voltage		0	3.6	V
Vo	output voltage	output HIGH or LOW state	0	V <sub>CC</sub>	V
		output 3-state	0	3.6	V
		power-down mode; $V_{CC}$ = 0 V	0	3.6	V
T <sub>amb</sub>	ambient temperature	in free air	-40	+85	°C
Δt/ΔV	input transition rise and fall rate	$V_{CC}$ = 1.65 V to 2.7 V	0	20	ns/V
		V <sub>CC</sub> = 2.7 V to 3.6 V	0	10	ns/V

### 9. Static characteristics

#### Table 6. Static characteristics

At recommended operating conditions. Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	T <sub>amb</sub> =	= -40 °C to	+85 °C	Unit	
			Min	Typ <mark>[1]</mark>	Max	]	
VIH	HIGH-level input voltage	V <sub>CC</sub> = 1.65 V to 1.95 V	0.65 × V <sub>CC</sub>	-	-	V	
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.7	-	-	V	
		V <sub>CC</sub> = 2.7 V to 3.6 V	2.0	-	-	V	
V <sub>IL</sub>	LOW-level input voltage	V <sub>CC</sub> = 1.65 V to 1.95 V	-	-	0.35 × V <sub>CC</sub>	V	
		V <sub>CC</sub> = 2.3 V to 2.7 V	-	-	0.7	V	
		V <sub>CC</sub> = 2.7 V to 3.6 V	-	-	0.8	V	
V <sub>OH</sub>	HIGH-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$					
		$I_{O}$ = -100 µA; $V_{CC}$ = 1.65 V to 3.6 V	V <sub>CC</sub> - 0.2	-	-	V	
		I <sub>O</sub> = -6 mA; V <sub>CC</sub> = 1.65 V	1.25	1.51	-	V	
		I <sub>O</sub> = -12 mA; V <sub>CC</sub> = 2.3 V	1.8	2.10	-	V	
		I <sub>O</sub> = -18 mA; V <sub>CC</sub> = 2.3 V	1.7	2.01	-	V	
		I <sub>O</sub> = -12 mA; V <sub>CC</sub> = 2.7 V	2.2	2.53	-	V	
		I <sub>O</sub> = -18 mA; V <sub>CC</sub> = 3.0 V	2.4	2.76	-	V	
	I <sub>O</sub> = -24 mA; V <sub>CC</sub> = 3.0 V	2.2	2.68	-	V		
V <sub>OL</sub>	LOW-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>					
		$I_{O}$ = 100 µA; $V_{CC}$ = 1.65 V to 3.6 V	-	-	0.2	V	
		I <sub>O</sub> = 6 mA; V <sub>CC</sub> = 1.65 V	-	0.11	0.3	V	
		I <sub>O</sub> = 12 mA; V <sub>CC</sub> = 2.3 V	-	0.17	0.4	V	
		I <sub>O</sub> = 18 mA; V <sub>CC</sub> = 2.3 V	-	0.25	0.6	V	
		I <sub>O</sub> = 12 mA; V <sub>CC</sub> = 2.7 V	-	0.16	0.4	V	
		I <sub>O</sub> = 18 mA; V <sub>CC</sub> = 3.0 V	-	0.23	0.4	V	
		I <sub>O</sub> = 24 mA; V <sub>CC</sub> = 3.0 V	-	0.30	0.55	V	
li –	input leakage current	V <sub>CC</sub> = 3.6 V; V <sub>I</sub> = 3.6 V or GND	-	±0.1	±5	μA	
I <sub>OFF</sub>	power-off leakage current	$V_{CC}$ = 0 V; V <sub>I</sub> or V <sub>O</sub> = 0 V to 3.6 V	-	±0.1	±10	μA	
I <sub>CC</sub>	supply current	$V_{CC}$ = 3.6 V; $V_{I}$ = $V_{CC}$ or GND; $I_{O}$ = 0 A	-	0.2	20	μA	
∆l <sub>CC</sub>	additional supply current	per input pin; $V_{CC}$ = 3.0 V to 3.6 V; V <sub>I</sub> = V <sub>CC</sub> - 0.6 V; I <sub>O</sub> = 0 A	-	5	750	μA	
Cı	input capacitance		-	3.5	-	pF	

[1] All typical values are measured at V<sub>CC</sub> = 3.3 V (unless stated otherwise) and T<sub>amb</sub> = 25 °C.

### **10.** Dynamic characteristics

#### Table 7. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V). For test circuit, see Fig. 7.

Symbol	Parameter	Conditions		T <sub>amb</sub> = -40 °C to +85 °C		Unit	
				Min	Typ[1]	Мах	
t <sub>pd</sub>	propagation delay	nA, nB to nY; see <u>Fig. 6</u>	[2]				
		V <sub>CC</sub> = 1.65 V to 1.95 V		1.0	2.8	4.4	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V		1.0	2.1	2.8	ns
		V <sub>CC</sub> = 2.7 V		1.0	2.6	3.2	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V		1.0	2.1	3.0	ns
C <sub>PD</sub>	power dissipation capacitance	per gate; V <sub>I</sub> = GND to V <sub>CC</sub> ; V <sub>CC</sub> = 3.3 V	per gate; $V_I$ = GND to $V_{CC}$ ; $V_{CC}$ = 3.3 V [3]		28	-	pF

[1] Typical values are measured at  $T_{amb} = 25 \degree C$ 

[2]  $t_{pd}$  is the same as  $t_{PHL}$  and  $t_{PLH}$ .

[3]  $C_{PD}$  is used to determine the dynamic power dissipation (P<sub>D</sub> in  $\mu$ W).

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_o)$  where:

 $f_i$  = input frequency in MHz;

f<sub>o</sub> = output frequency in MHz;

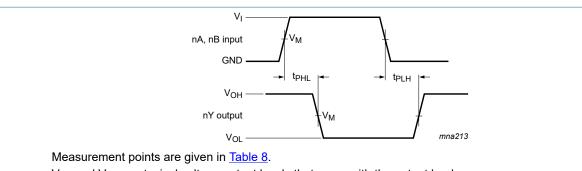
 $C_L$  = output load capacitance in pF;

V<sub>CC</sub> = supply voltage in volt;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_o)$  = sum of the outputs.

#### 10.1. Waveforms and test circuit



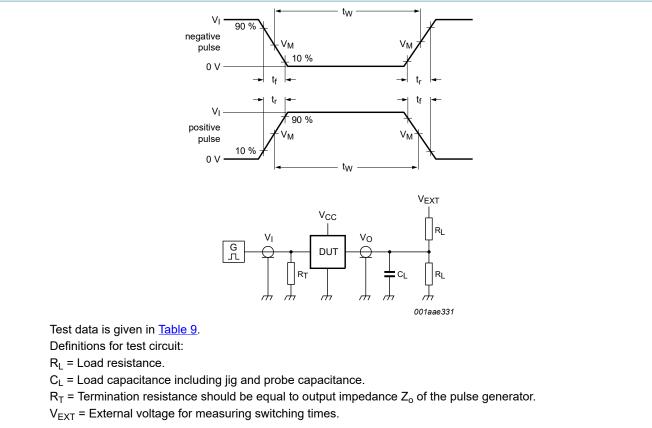
 $V_{\text{OL}}$  and  $V_{\text{OH}}$  are typical voltage output levels that occur with the output load.

#### Fig. 6. Inputs nA, nB to output nY propagation delay times

#### Table 8. Measurement points

Supply voltage V <sub>CC</sub>	Input V <sub>I</sub>	V <sub>M</sub>
1.65 V to 1.95 V	Vcc	0.5V <sub>CC</sub>
2.3 V to 2.7 V	V <sub>CC</sub>	0.5V <sub>CC</sub>
2.7 V	2.7 V	1.5 V
3.0 V to 3.6 V	2.7 V	1.5 V

#### **Quad 2-input NAND gate**



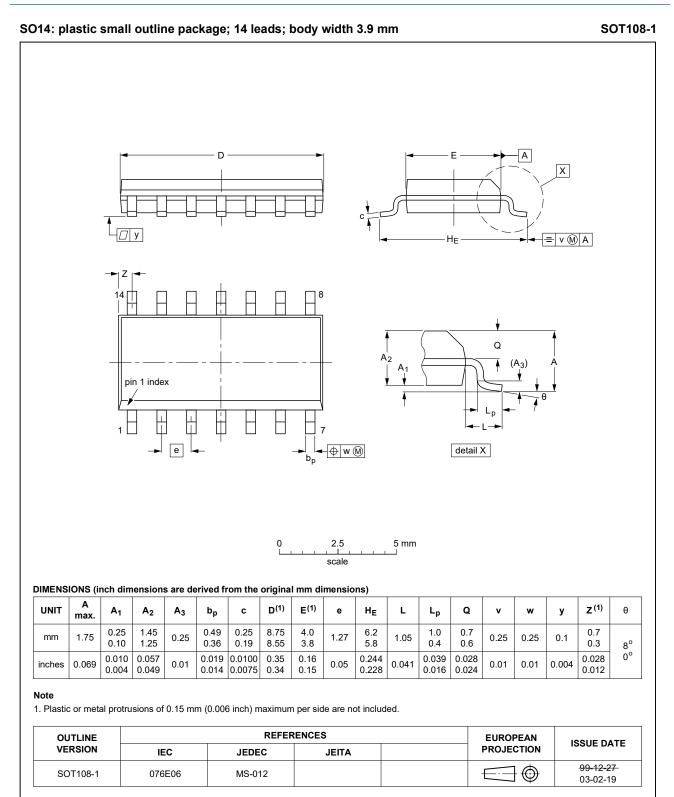
#### Fig. 7. Test circuit for measuring switching times

#### Table 9. Test data

Supply voltage $V_{\text{CC}}$	Input	Input			V <sub>EXT</sub>		
	VI	t <sub>r</sub> , t <sub>f</sub>	CL	RL	t <sub>PLH</sub> , t <sub>PHL</sub>	t <sub>PLZ</sub> , t <sub>PZL</sub>	t <sub>PHZ</sub> , t <sub>PZH</sub>
1.65 V to 1.95 V	V <sub>CC</sub>	≤ 2.0 ns	30 pF	1 kΩ	open	2 x V <sub>CC</sub>	GND
2.3 V to 2.7 V	V <sub>CC</sub>	≤ 2.0 ns	30 pF	500 Ω	open	2 x V <sub>CC</sub>	GND
2.7 V	2.7 V	≤ 2.5 ns	50 pF	500 Ω	open	6 V	GND
3.0 V to 3.6 V	2.7 V	≤ 2.5 ns	50 pF	500 Ω	open	6 V	GND

#### **Quad 2-input NAND gate**

### 11. Package outline



#### Fig. 8. Package outline SOT108-1 (SO14)

#### **Quad 2-input NAND gate**

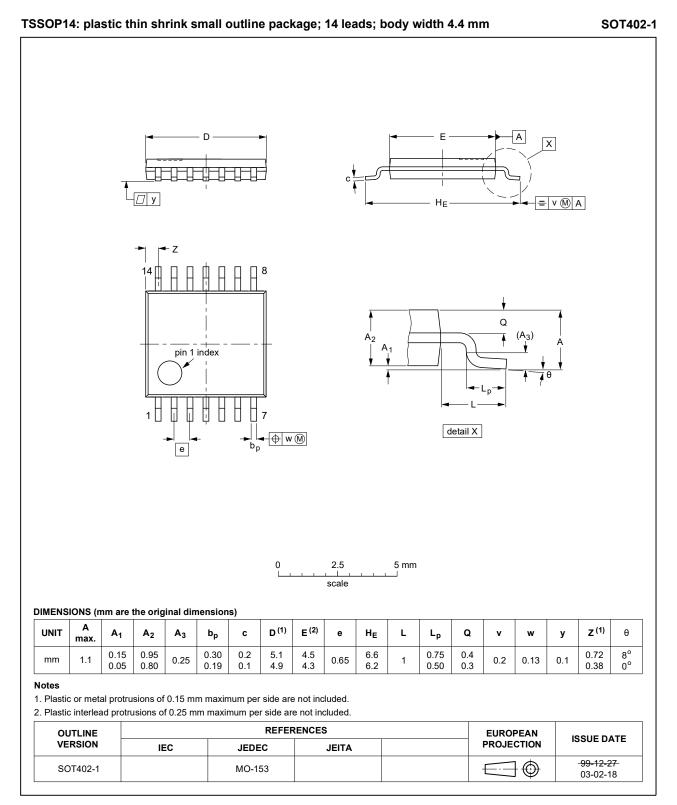


Fig. 9. Package outline SOT402-1 (TSSOP14)

<sup>74</sup>ALVC00\_Q100

#### **Quad 2-input NAND gate**

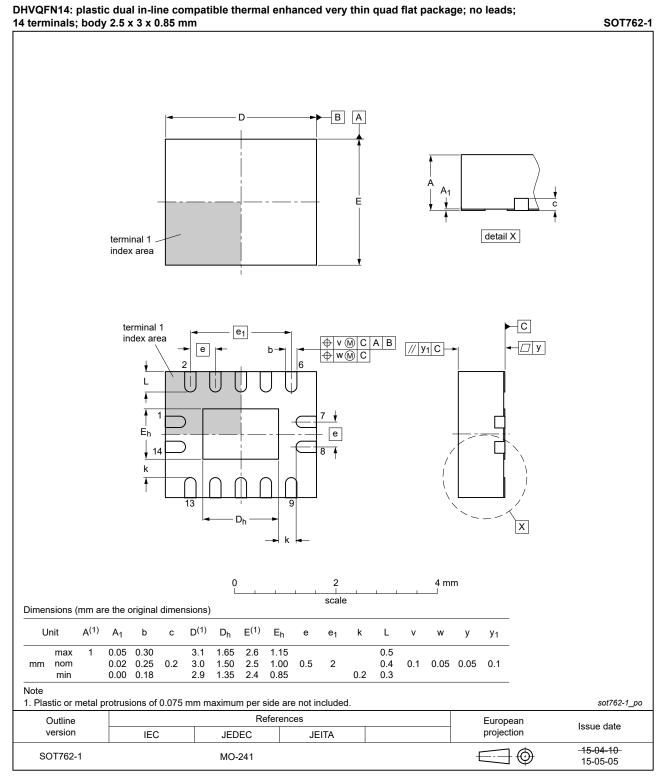


Fig. 10. Package outline SOT762-1 (DHVQFN14)

### 12. Abbreviations

Acronym	Description	
CMOS	Complementary Metal-Oxide Semiconductor	
DUT	Device Under Test	
ESD	ElectroStatic Discharge	
HBM	Human Body Model	
MIL	Military	
MM	Machine Model	
TTL	Transistor-Transistor Logic	

### 13. Revision history

#### Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes	
74ALVC00_Q100 v.3	20210430	Product data sheet	-	74ALVC00_Q100 v.2	
Modifications:	<ul> <li><u>Section 2</u>: Reference to JESD36 removed.</li> <li><u>Table 4</u>: Derating values for P<sub>tot</sub> total power dissipation updated (errata).</li> </ul>				
74ALVC00_Q100 v.2	20200921	Product data sheet	-	74ALVC00_Q100 v.1	
Modifications:	<ul> <li>The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia.</li> <li>Legal texts have been adapted to the new company name where appropriate.</li> <li><u>Section 2</u> updated.</li> <li><u>Table 4</u>: Derating values for P<sub>tot</sub> total power dissipation have been updated.</li> <li>Package outline drawing of SOT762-1 (Fig. 10) updated.</li> </ul>				
74ALVC00_Q100 v.1	20140516	Product data sheet	-	-	

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#### Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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